

Diodes type D62 are of modern design with internal spring loaded contacts and pressure welded glass-to-metal seal. Designed for use in power electronic circuits and equipment under normal operating conditions.

**KEY PARAMETERS**

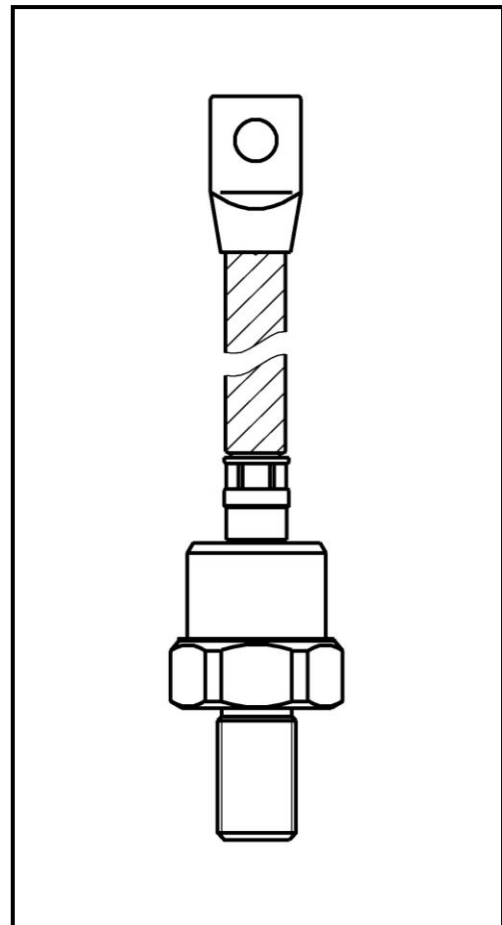
$U_{RRM}$	up to 1600 V
$I_{F(AV)}$	400 A
$I_{FSM}$	7000 A

**FEATURES**

- all diffused design
- high current capabilities
- high surge current capabilities
- high rates voltages
- low thermal impedance
- tested according to IEC standards
- compact size and small weight

**APPLICATION**

- High Voltage Power Supplies
- Motor Control
- Battery Chargers
- Free Wheeling Diode
- Resistance Welding



Outline type code: JEDEC DO-205AB

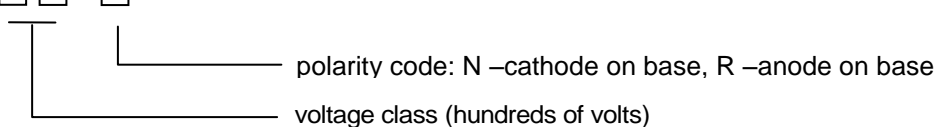
See package details for further information

Designed for use in high power industrial and commercial power electronic circuits and equipment where high currents are encountered and high reliability is essential.

**ORDERING INFORMATION**

When ordering please refer to device code builder presented below.  
Please use the complete part number when ordering, quote or in any future correspondence relating to your order.

**D62-400-□□-□0**



**ELECTRICAL PARAMETERS**

**Voltage ratings**

Voltage class	$U_{RRM}$	$U_{RSM}$	$I_{RRM}$
	V	V	mA
04	400	500	50
06	600	700	
08	800	900	
10	1000	1100	
12	1200	1300	
14	1400	1500	
16	1600	1700	

**Electrical properties**

Parameter		Unit	Test conditions	Value
Average forward current @ case temperature	$I_{F(AV)}$	A		400
	$T_c$	°C		$U_{RRM} \leq 1200V$ 125 $U_{RRM} > 1200V$ 110
RMS forward current	$I_{F(RMS)}$	A		628
Surge current	$I_{FSM}$	A	$T_j = T_{jmax}$ , $U_R = 0,8U_{RRM}$ , $t_p = 10ms$	7000
$I^2t$ – value	$I^2t$	$kA^2s$		245
Forward voltage drop max.	$U_{FM}$	V	$T_j = 25^\circ C$ , $I_{FM} = 800A$	1,20
Threshold voltage	$U_{F(T0)}$	V		0,62
Slope resistance	$r_F$	$m\Omega$		0,563

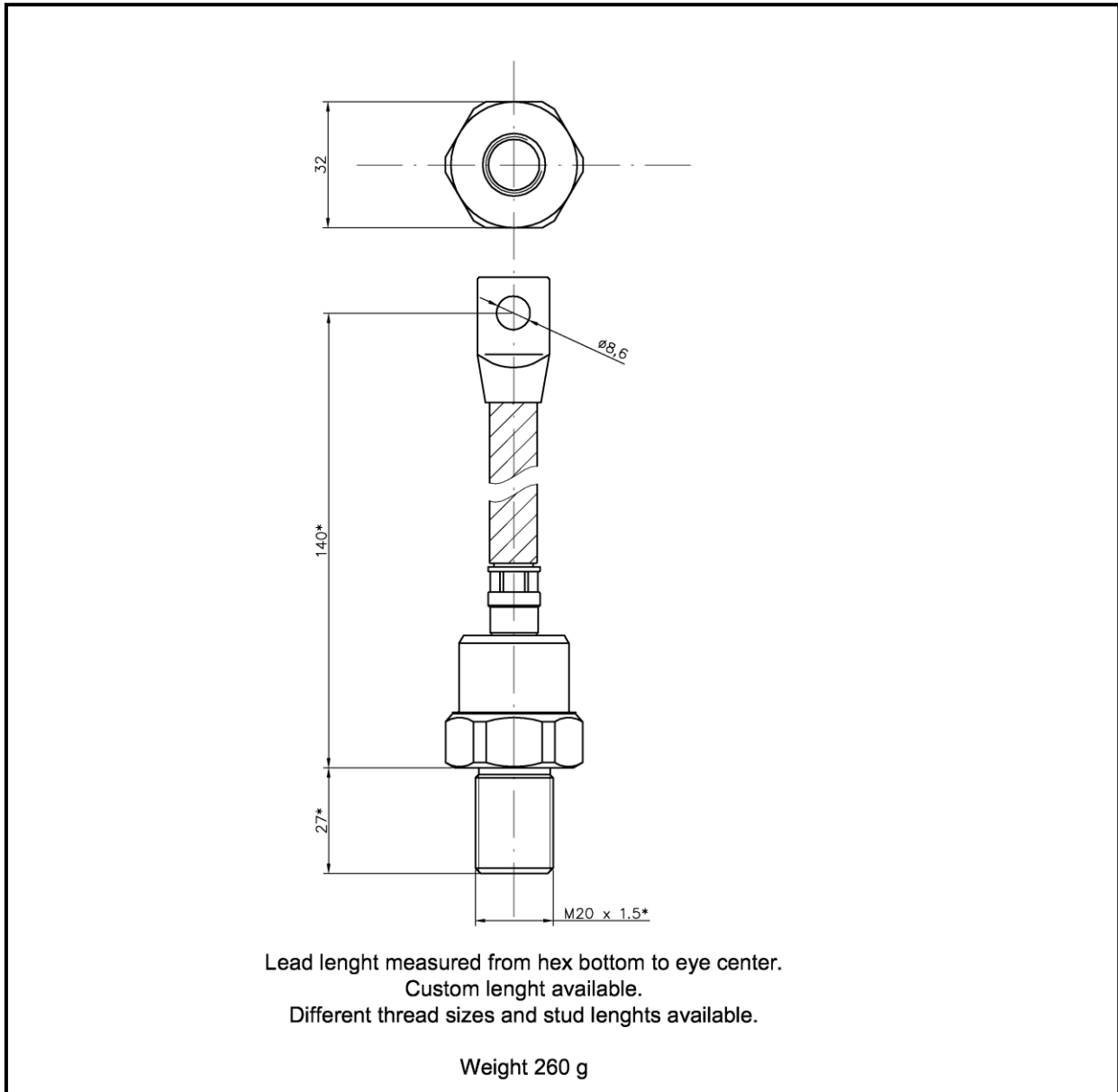
**Thermal properties**

Parameter		Unit	Test conditions	Value
Thermal resistance, junction to case	$R_{thJC}$	°C/W	DC	0,12
Thermal resistance, case to heatsink	$R_{thCS}$	°C/W		0,10
Operating junction temperature	$T_{jmin} \dots T_{jmax}$	°C		$U_{RRM} \leq 1200V$ -40...+190 $U_{RRM} > 1200V$ -40...+175
Storage temperature	$T_{stg}$	°C		-40...+190

**Mechanical properties**

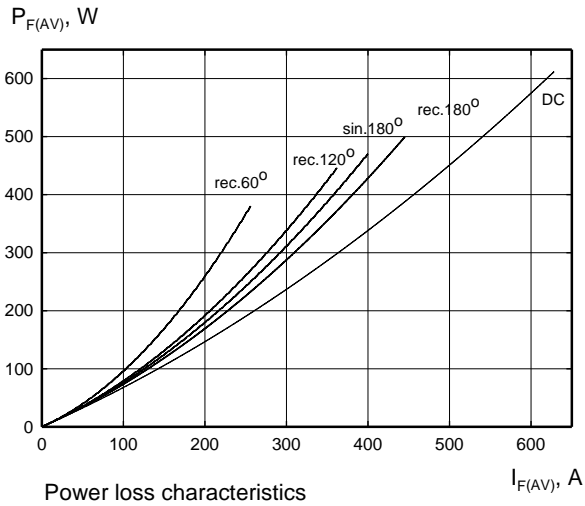
Parameter		Unit	Value
Mounting torque	M	Nm	28 ... 32
Weight	m	g	260

**Package details**

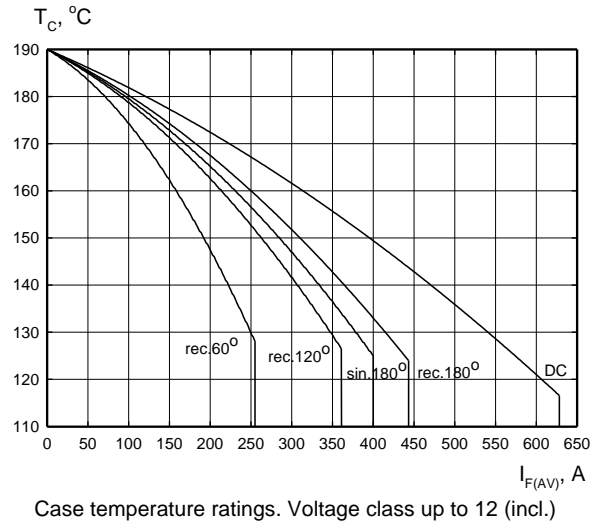


For further package information, please contact Sales & Marketing Department. All dimensions in mm, unless stated otherwise.  
Do not scale.

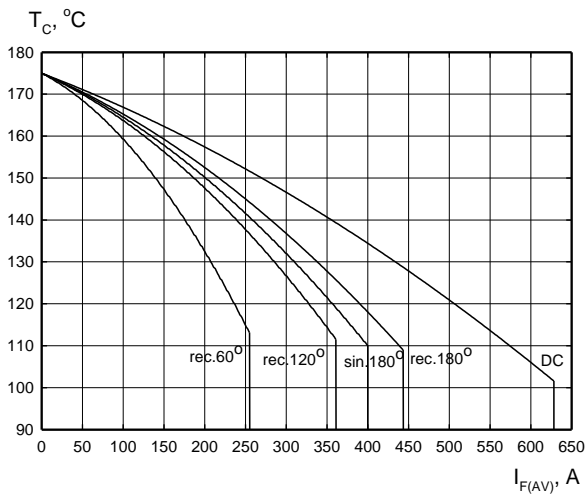
**CHARACTERISTICS**



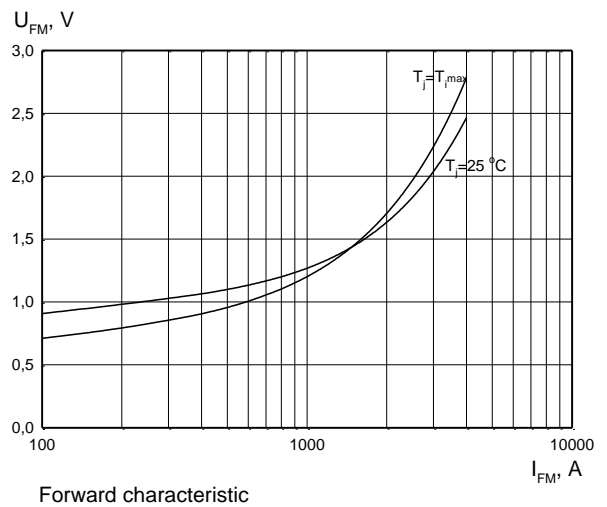
Power loss characteristics



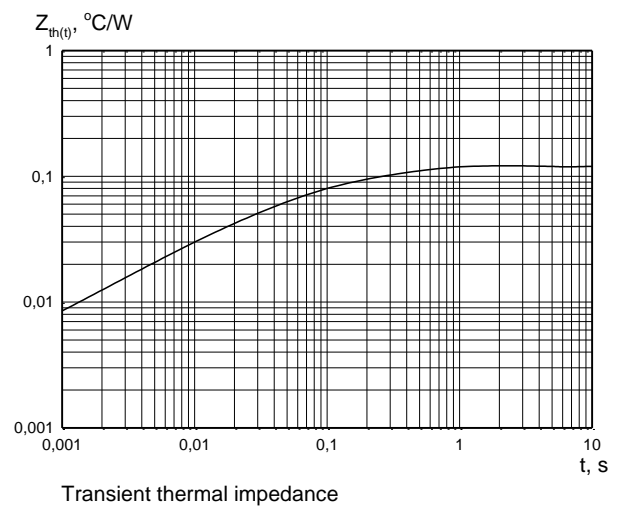
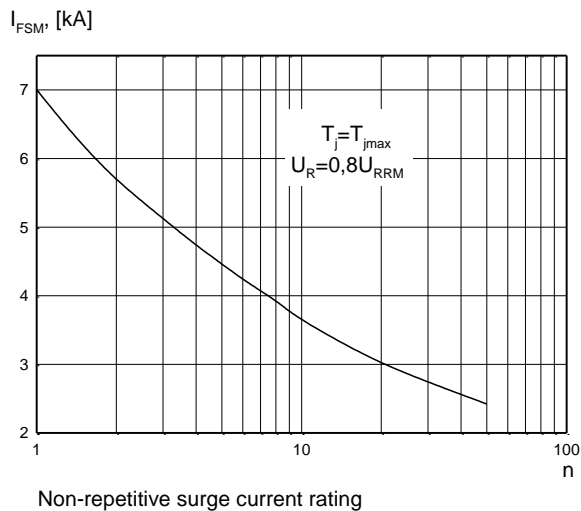
Case temperature ratings. Voltage class up to 12 (incl.)



Case temperature ratings. Voltage class > 12



Forward characteristic



## HEATSINKS

**KUBARA LAMINA SA** has its own proprietary range of extruded aluminium heatsinks designed to optimise the performance of our semiconductors with natural and forced air flow.

## POWER ASSEMBLY CAPABILITY

**KUBARA LAMINA SA** provides a support for those customers requiring more than a basic semiconductor and offers precisely assembled Power Blocks according to factory or customer standards.